

	Type	Hits	Search Text
1	BRS	3	(n adj3 type) adj3 (residual or residue or residues) adj3 (diffused or diffusion or diffuse)
2	BRS	232	(ion adj3 implanting) near10 (diffused)

	DBs	Time Stamp
1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/20 08:16
2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/20 08:19

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	IS&R	L1	1	("5378903").PN.	USPAT	2002/09/20 10:28
2	BRS	L2	2291	p adj3 type adj3 emitter	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/09/20 10:29
3	BRS	L3	82	2 and (diffused adj3 n adj3 layer)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/09/20 10:32

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	IS&R	L1	1	("4278476").PN.	USPAT	2002/09/20 14:14
2	BRS	L2	7539	(n adj3 type) adj substrate	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/09/20 13:52
3	BRS	L3	64	2 and (diffused adj3 n adj3 layer)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/09/20 13:54
4	IS&R	L4	1	("5378903").PN.	USPAT	2002/09/20 14:06
5	BRS	L5	0	(backside adj3 p adj3 emitter) same (ion adj3 implanting)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/09/20 14:15
6	BRS	L6	0	(backside adj3 p adj3 emitter) and (ion adj3 implanting)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/09/20 14:16

	Type	L #	Hits	Search Text	DBs	Time Stamp
7	BRS	L7	0	backside adj3 p adj3 emitter	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/09/20 14:16
8	BRS	L8	13	(p adj3 emitter) same (ion adj implanting)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/09/20 14:30
9	BRS	L9	0	8 and (low adj3 temperature)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/09/20 14:30
10	BRS	L10	3	8 and temperature	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/09/20 14:32
11	BRS	L12	1	(sintering same alloying) same (depositing same metals)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/09/20 14:36

	Type	L #	Hits	Search Text	DBs	Time Stamp
12	BRS	L13	4	sintering/alloying	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/09/20 14:36